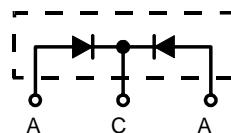


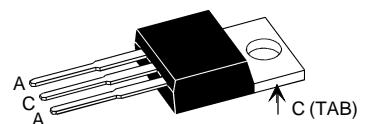
## HiPerFRED™ Epitaxial Diode with common cathode and soft recovery

$I_{FAV} = 2 \times 5 \text{ A}$   
 $V_{RRM} = 200 \text{ V}$   
 $t_{rr} = 25 \text{ ns}$

$V_{RSM}$ V	$V_{RRM}$ V	Type
200	200	DSEC 10-02A



TO-220 AB



A = Anode, C = Cathode, TAB = Cathode

Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$		35	A
$I_{FAVM}$	$T_C = 160^\circ\text{C}$ ; rectangular, $d = 0.5$	5	A
$I_{FRM}$	$t_p < 10 \mu\text{s}$ ; rep. rating, pulse width limited by $T_{VJM}$	tbd	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sine	80	A
$E_{AS}$	$T_{VJ} = 25^\circ\text{C}$ ; non-repetitive $I_{AS} = 2 \text{ A}$ ; $L = 180 \mu\text{H}$	0.5	mJ
$I_{AR}$	$V_A = 1.5 \cdot V_R$ typ.; $f = 10 \text{ kHz}$ ; repetitive	0.2	A
$T_{VJ}$		-55...+175	°C
$T_{VJM}$		175	°C
$T_{stg}$		-55...+150	°C
$P_{tot}$	$T_C = 25^\circ\text{C}$	60	W
$M_d$	mounting torque	0.4...0.6	Nm
Weight	typical	2	g

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$ ①	$T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$ $T_{VJ} = 150^\circ\text{C}$ $V_R = V_{RRM}$	50 0.2	$\mu\text{A}$ mA
$V_F$ ②	$I_F = 5 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$	0.81 1.23	V V
$R_{thJC}$ $R_{thCH}$		0.5	K/W K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 50 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	25	ns
$I_{RM}$	$V_R = 100 \text{ V}$ ; $I_F = 10 \text{ A}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$ $T_{VJ} = 100^\circ\text{C}$	2.0	A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %  
 ② Pulse Width = 300  $\mu\text{s}$ , Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, test conditions and dimensions.